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U.S. Department of Commerce, Patent and Trademark Office					Atty Dock	et No.	Serial No.		
					2003-0105	-02	10/781,251		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT					Applicant(s)				
(Use several sheets if necessary)					Palash Das, et al.				
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Examiner Initial		Document Number	Date	Name	Class	Subclass		z Date ropriate	
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RBS	В	4,455,658	6/19/84	Sutter, et al.	372	38			
MB3	C	4,618,759	10/21/86	Muller, et al.	219	121			
RBYS.	D	4,959,840	9/25/90	Robert Akins, et al.	372	57			
RB¥	P	5,023,884	6/11/91	Robert Akins, et al.	372	57		_	
RBZ	P	5,025,445	6/18/91	Anderson, et al.	372	20			
RBY	G	5,025,446	6/18/91	Dirk J. Kuizenga	372	21			
RBY	H	5,189,678	2/23/93	Ball, et al.	372	28			
RB F	I	5,313,481	5/17/94	Cook, et al.	372	37			
RBZ	J	5,315,611	5/24/94	Ball, et al.	372	56			
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RB3	L	5,448,580	9/5/95	Birx, et al.	372	38			
RBY	М	5,471,965	12/5/95	Davorin D. Kapich	123	565			
RBF	N	5,852,621	12/22/98	Richard L. Sandstrom	372	25			
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RBZ	P	5,953,360	9/14/99	Vitruk, et al.	372	87			
RBZ	Q	5,978,394	11/2/99	Newman, et al.	372	32			
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RBY	T	6,016,325	1/18/00	Ness, et al.	372	38		•	
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PAGE 5/43 \* RCVD AT 6/14/2004 3:02:32 PAI [Eastern Daylight Time] \* SVR: USPTO-EFXRF-1/1 \* DHIS:8729306 \* CSID: \* DURATION (mix/ss):22-16

RMAT		E STATEMENT E	BY APPLICANT	2003-0105 Applicant( Palash Das		10/781,25	1		
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Y	6,094,448	7/25/00	Fomenkov, et al.	372	102	<del> </del>			
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AC	6,151,349	11/21/00							
AD	6,164,116	12/26/00	·						
AE	6,192,064	2/20/01		_					
AF	6,208,674	3/27/01	Webb, et al.	372					
AG	6,208,675	3/27/01	R. Kyle Webb	372					
AH	6,212,211	4/3/01		372	<del></del>				
AI	6,219,368	4/17/01	<del>                                     </del>			ļ			
ΑJ	6,240,117	5/29/01	Gong, et al.	372	58				
AK	6,317,447	11/13/01	Partio, et al.	372	57				
AL	6,330,261	12/11/01	Ishihara, et al.	372	38.1				
AM	6,414,979	7/2/02	Ujazdowski, et al.	372	87				
AN	6,477,193	11/5/02	Oliver, et al.	372	58		-		
AO	6,549,551	4/15/03	Ness, et al.	372	38				
AP	6,567,450	5/20/03	Myers, et al.	372	55				
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INFORMATION DISCLOSURE STATEMENT BY APPLICANT					Applicant(s)				
(Use several sheets if necessary)					Palash Das, et al.				
					Filing Date		Group		
					February 18, 2004		Unassigned		
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RBY	AR	6,625,191	9/23/03	Knowles, et al.	372	55			
RBZ	AS	09/451,995	11/30/99	Hofmann, et al.		•	1		
RBS	AT	10/606,412	6/25/03	Saethre, et al.					
ROZ	AU	10/607,407	6/25/03	Ness, et al.		•			
RBY	ΑV	10/712,545	11/13/03	R. Kyle Webb, et al.					
RBY	AW	2002/0021728	2/21/02	Newman, et al.	372	55			
RB3	AX	2002/0167986	11/14/02	Pan, et al.	372	55			
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